

PNP -0.7A -80V Middle Power Transistor

Parameter	Value
V_{CEO}	-80V
I _C	-0.7A

Features

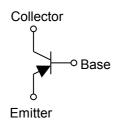
- 1) Suitable for Middle Power Driver
- 2) Complementary NPN Types: 2SCR514P
- 3) Low V_{CE(sat)}

$$V_{CE(sat)} = -0.4V(Max.)$$

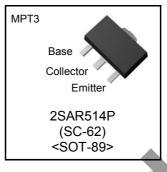
 $(I_C/I_B = -300mA/-15mA)$

4) Lead Free/RoHS Compliant.

•Inner circuit



Outline



Applications

Motor driver , LED driver Power supply

Packaging specifications

Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
2SAR514P	MPT3	4540	T100	180	12	1,000	MD

● Absolute maximum ratings (Ta = 25°C)

Parameter		Values	Unit
Collector-base voltage		-80	V
Collector-emitter voltage		-80	V
Emitter-base voltage		-6	V
DC	I _C	-0.7	А
Pulsed	I _{CP} *1	-1.4	А
Power dissipation		0.5	W
		2.0	W
Junction temperature		150	°C
Range of storage temperature		−55 to +150	°C
	DC Pulsed	$\begin{array}{c c} & V_{CBO} \\ \hline & V_{CEO} \\ \hline & V_{EBO} \\ \hline \\ DC & I_C \\ \hline Pulsed & I_{CP}^{*1} \\ \hline & P_D^{*2} \\ \hline & P_D^{*3} \\ \hline & T_j \\ \hline \end{array}$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$

^{*1} Pw=10ms, single pulse

^{*2} Each terminal mounted on a reference land

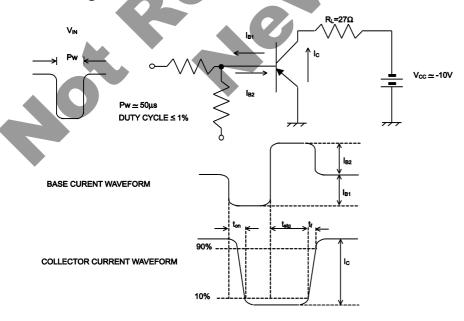
^{*3} Mounted on a ceramic board (40×40×0.7mm)

●Electrical characteristics(Ta = 25°C)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector-emitter breakdown voltage	BV _{CEO}	I _C = -1mA	-80	-	-	V
Collector-base breakdown voltage	BV _{CBO}	$I_{C} = -100 \mu A$	-80	-	-	V
Emitter-base breakdown voltage	BV _{EBO}	$I_E = -100 \mu A$	-6	ı	-	V
Collector cut-off current	I _{CBO}	V _{CB} = -80V	ı	-	1	μА
Emitter cut-off current	I _{EBO}	V _{EB} = -4V	-	-	-1	μΑ
Collector-emitter saturation voltage	V _{CE(sat)} *1	$I_C = -300 \text{mA}, I_B = -15 \text{mA}$		-0.20	-0.40	V
DC current gain	h _{FE}	$V_{CE} = -3V$, $I_{C} = -100$ mA	120	-	390	-
Transition frequency	f _⊤	$V_{CE} = -10V, I_{E} = -200 \text{mA}$ f=100MH _Z	-	380	-	MHz
Output capacitance	C _{ob}	$V_{CB} = -10V, I_{E} = 0A,$ f = 1MHz	-	10	-	pF
Turn-on time	t _{on} *2	I _C = -0.35A	C	50	-	ns
Storage time	t _{stg} *2	I _{B1} = -35mA I _{B2} =35mA	-	350	-	ns
Fall time	t _f *2	V _{CC} [≃] −10V	-	50	-	ns

^{*1} Pulsed

•Switching time test circuit



^{*2} See switching time test circuit

●Electrical characteristic curves(Ta = 25°C)

Fig.1 Ground Emitter Propagation Characteristics

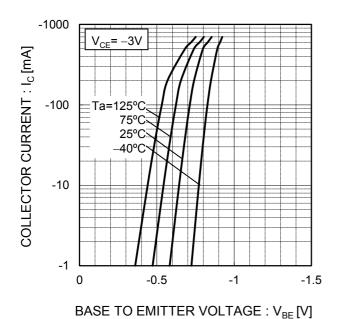
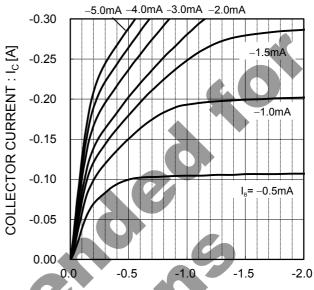


Fig.2 Typical Output Characteristics



COLECTOR TO EMITTE VOLTAGE : V_{CE} [V]

Fig.3 DC Current Gain vs. Collector Current(I)

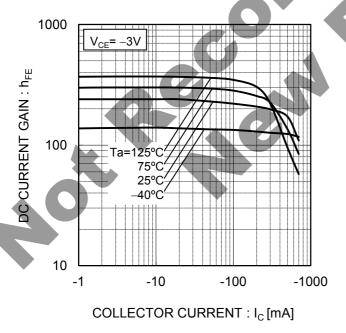
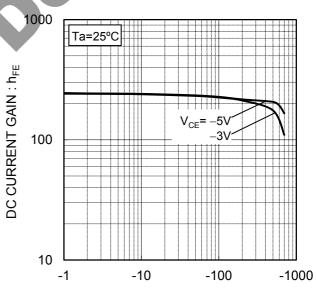


Fig.4 DC current gain vs. output current (II)



COLLECTOR CURRENT : I_C [mA]

●Electrical characteristic curves(Ta = 25°C)

Fig.5 Collector-Emitter Saturation Voltage

COLLECTOR CURRENT : I_C [mA]

vs. Collector Current (II)

Ta=25°C

Ta=25°C

Ta=25°C

To Ta=25°C

Fig.6 Collector-Emitter Saturation Voltage

Fig.7 Base-Emitter Saturation Voltage vs. Collector Current -10 $I_{\rm C}/I_{\rm B}=20$ BASE-EMITTER SATURATION VOLTAGE : V_{BE(sat)} [V] Pulsed -40°C 25°C 75°C 125°C -0.1 -1 -10 -100 -1000 COLLECTOR CURRENT: Ic [mA]

Fig.8 Gain Bandwidth Product
vs. Emitter Current

1000

Ta=25°C
V_{CE}= -10V

10

10

10

To
1000

EMITTER CURRENT: I_E [mA]

●Electrical characteristic curves(Ta = 25°C)

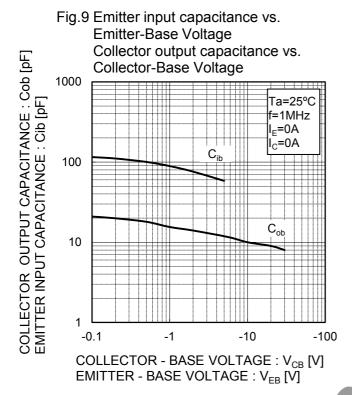
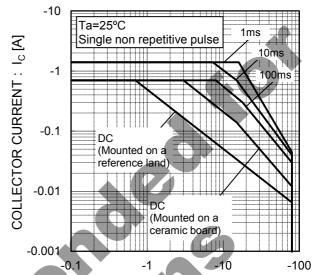


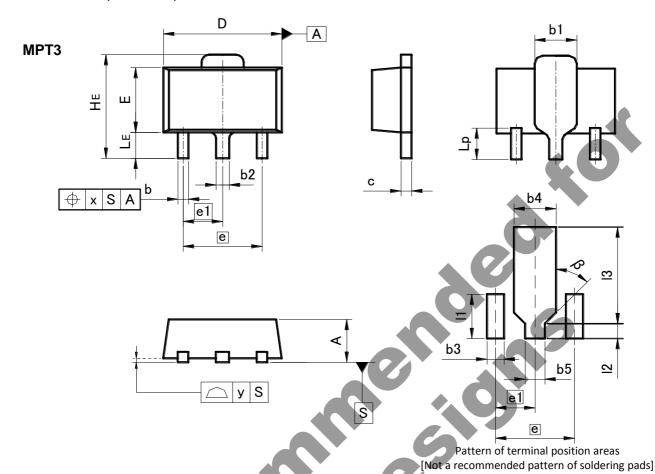
Fig.10 Safe Operating Area



COLLECTOR TO EMITTER VOLTAGE : V_{CE} [V]



●Dimensions (Unit : mm)



		·			
DIM	MILIM	ETERS	INCHES		
DIIVI	MIN	MAX	MIN	MAX	
Α	1.40	1.50	0.055	0.059	
b	0.30	0.50	0.012	0.020	
b1	1.50	1.70	0.059	0.067	
b2	0.40	0.60	0.016	0.024	
C	0.35	0.50	0.014	0.020	
D	4.40	4.70	0.173	0.185	
E	2.40	2.70	0.094	0.106	
е	3.0	00	0.118		
e1	1.	50	0.059		
HE	3.70	4.30	0.146	0.169	
LE	0.80	1.20	0.031	0.047	
Lp	1.01	1.41	0.040	0.056	
Х	ı	0.15	1	0.006	
У		0.10	-	0.004	

DIM	MILIM	ETERS	INCHES		
	MIN	MAX	MIN	MAX	
b3	-	0.65	ı	0.026	
b4	_	1.70	-	0.067	
b5		0.75	I	0.030	
l1	_	1.71	I	0.067	
12	_	0.58	I	0.023	
13	_	3.72	-	0.146	
β	45°		45	0	

Dimension in mm / inches

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